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### LINKS TO ADDITIONAL RESOURCES



SHAY

| PRIMARY CHARACTERISTICS          |                     |  |  |  |  |
|----------------------------------|---------------------|--|--|--|--|
| I <sub>F(AV)</sub>               | 2 x 3 A             |  |  |  |  |
| V <sub>R</sub>                   | 100 V               |  |  |  |  |
| V <sub>F</sub> at I <sub>F</sub> | 0.75 V              |  |  |  |  |
| t <sub>rr</sub> (typ.)           | 20 ns               |  |  |  |  |
| T <sub>J</sub> max.              | 175 °C              |  |  |  |  |
| Package                          | SlimDPAK (TO-252AE) |  |  |  |  |
| Circuit configuration            | Common cathode      |  |  |  |  |

## FEATURES

- Hyperfast recovery time
- Low forward voltage drop reduced Q<sub>rr</sub> and soft recovery
- Low leakage current
- Very low profile typical height of 1.3 mm
- 175 °C operating junction temperature
- Ideal for automated placement
- AEC-Q101 qualified, meets JESD 201 class 2 whisker test
- Polyimide passivation for high reliability standard
- Meets MSL level 1, per J-STD-020, LF maximum peak of 260 °C
- Material categorization: for definitions of compliance please see <u>www.vishay.com/doc?99912</u>

### **DESCRIPTION / APPLICATIONS**

State of the art hyper fast recovery rectifiers designed with optimized performance of forward voltage drop and hyper fast recovery time.

The planar structure and the platinum doped life time control guarantee the best overall performance, ruggedness and reliability characteristics.

These devices are intended for use in PFC boost stage in the AC/DC section of SMPS inverters or as freewheeling diodes. Their extremely optimized stored charge and low recovery current minimize the switching losses and reduce over dissipation in the switching element and snubbers.

### **MECHANICAL DATA**

Case: SlimDPAK (TO-252AE)

Molding compound meets UL 94 V-0 flammability rating Halogen-free, RoHS-compliant

Terminals: matte tin plated leads, solderable per J-STD-002

| ABSOLUTE MAXIMUM RATINGS            |            |                                   |  |             |       |  |
|-------------------------------------|------------|-----------------------------------|--|-------------|-------|--|
| PARAMETER                           |            | SYMBOL                            | TEST CONDITIONS                            | MAX.        | UNITS |  |
| Peak repetitive reverse voltage     |            | V <sub>RRM</sub>                  |  | 100         | V     |  |
| Average rectified forward current   | per leg    |                                   | Total device, rated $V_R$ , $T_C$ = 166 °C | 3           |       |  |
| Average rectilied forward current   | per device | IF(AV)                            |  | 6           | А     |  |
| Non-repetitive peak surge current   | per leg    | I <sub>FSM</sub>                  | $T_J$ = 25 °C, 10 ms sine pulse wave       | 70          |       |  |
| Operating junction and storage terr | peratures  | T <sub>J</sub> , T <sub>Stg</sub> |  | -55 to +175 | °C    |  |

| <b>ELECTRICAL SPECIFICATIONS</b> (T <sub>J</sub> = 25 °C unless otherwise specified) |                 |   |      |      |      |       |
|--|-----------------|---|------|------|------|-------|
| PARAMETER  | SYMBOL          | TEST CONDITIONS                                 | MIN. | TYP. | MAX. | UNITS |
| Breakdown voltage, blocking voltage  | $V_{BR}, V_{R}$ | I <sub>R</sub> = 100 μA                         | 100  | -    | -    |       |
|  |                 | I <sub>F</sub> = 3 A                            | -    | 0.9  | 1.04 |       |
| Forward voltage  | V <sub>F</sub>  | I <sub>F</sub> = 3 A, T <sub>J</sub> = 150 °C   | -    | 0.75 | 0.82 | V     |
|  |                 | I <sub>F</sub> = 6 A                            | -    | 1    | 1.2  |       |
|  |                 | I <sub>F</sub> = 6 A, T <sub>J</sub> = 150 °C   | -    | 0.85 | 1.01 |       |
| Deverse leakerse eurrent   | 1               | $V_{R} = V_{R}$ rated                           | -    | -    | 5    | μA    |
| Reverse leakage current  | I <sub>R</sub>  | $T_J = 150 \text{ °C}, V_R = V_R \text{ rated}$ | -    | -    | 80   |       |
| Junction capacitance   | CT              | V <sub>R</sub> = 100 V                          | -    | 12   | -    | pF    |

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e3 RoHS COMPLIANT HALOGEN

FREE

AUTOMOTIVE



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# Vishay Semiconductors

| <b>DYNAMIC RECOVERY CHARACTERISTICS</b> ( $T_J = 25$ °C unless otherwise specified) |                  |  |  |      |      |       |         |  |
|---|------------------|--|--|------|------|-------|---------|--|
| PARAMETER   | SYMBOL           | TEST CO  | MIN.   | TYP. | MAX. | UNITS |         |  |
|   |                  | $I_F = 1.0 \text{ A}, \text{ d}I_F/\text{d}t = 50$                     | A/ $\mu$ s, V <sub>R</sub> = 30 V                        | -    | 20   | -     |         |  |
| Reverse recovery time   | +                | I <sub>F</sub> = 0.5 A, I <sub>R</sub> = 1 A, I <sub>RR</sub> = 0.25 A |  | -    | -    | 25    |         |  |
| neverse recovery time   | t <sub>rr</sub>  | T <sub>J</sub> = 25 °C   |  | -    | 17   | -     | A<br>nC |  |
|   |                  | T <sub>J</sub> = 125 °C  |  | -    | 26   | -     |         |  |
| Back receiver ( ourrent   |                  | T <sub>J</sub> = 25 °C   | $I_F = 3 A$  | -    | 1.8  | -     |         |  |
| Peak recovery current   | I <sub>RRM</sub> | T <sub>J</sub> = 125 °C  | dl <sub>F</sub> /dt = 200 A/µs<br>V <sub>B</sub> = 160 V | -    | 3.2  | -     |         |  |
| Reverse recovery charge   | Q <sub>rr</sub>  | T <sub>J</sub> = 25 °C   |  | -    | 15   | -     |         |  |
|   |                  | T <sub>J</sub> = 125 °C  | ]  | -    | 41   | -     |         |  |

| THERMAL - MECHANICAL SPECIFICATIONS            |                                     |                                |      |      |      |       |  |
|--|-------------------------------------|--------------------------------|------|------|------|-------|--|
| PARAMETER                                      | SYMBOL                              | TEST CONDITIONS                | MIN. | TYP. | MAX. | UNITS |  |
| Maximum junction and storage temperature range | T <sub>J</sub> , T <sub>Stg</sub>   |                                | -55  | -    | 175  | °C    |  |
| Thermal resistance, junction to ambient        | R <sub>thJA</sub> <sup>(1)(2)</sup> |                                | -    | 75   | 90   | °C/W  |  |
| Thermal resistance, junction to mount per leg  | R <sub>thJM</sub> <sup>(3)</sup>    |                                | -    | 3.2  | 4    | °C/W  |  |
| Weight   |                                     |                                | -    | 0.20 | -    | g     |  |
| Marking device                                 |                                     | Case style SlimDPAK (TO-252AE) |      | 6CV  | 'H01 |       |  |

#### Notes

- $^{(1)}$  The heat generated must be less than thermal conductivity from junction-to-ambient;  $dP_D/dT_J < 1R_{thJA}$
- <sup>(2)</sup> Free air, mounted or recommended copper pad area; thermal resistance R<sub>thJA</sub> junction to ambient

<sup>(3)</sup> Mounted on infinite heatsink

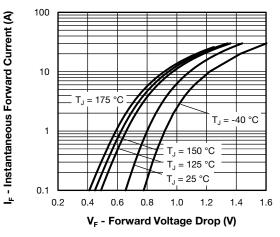


Fig. 1 - Typical Forward Voltage Drop Characteristics

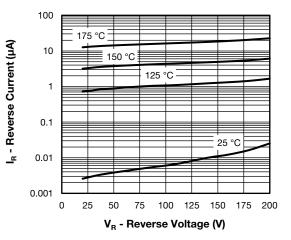


Fig. 2 - Typical Values of Reverse Current vs. Reverse Voltage

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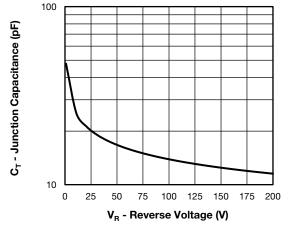


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage

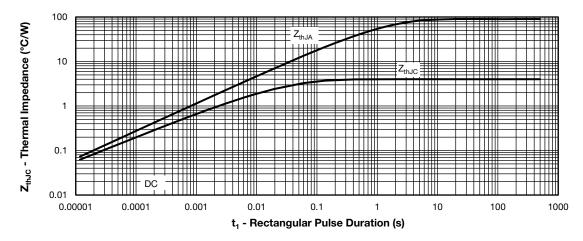
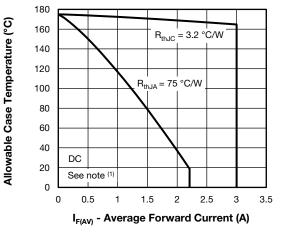
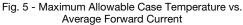


Fig. 4 - Maximum Thermal Impedance Z<sub>thJC</sub> Characteristics

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#### Note

4.5 RMS limit 4 Average Power Loss (W) 3.5 3 2.5 D = 0.02 D = 0.05 2 D = 0.1 D = 0.2 1.5 D = 0.5 1 DC 0.5 0 0 0.5 1 1.5 2 2.5 3 3.5 4 4.5 5 I<sub>F(AV)</sub> - Average Forward Current (A)

Fig. 6 - Forward Power Loss Characteristics

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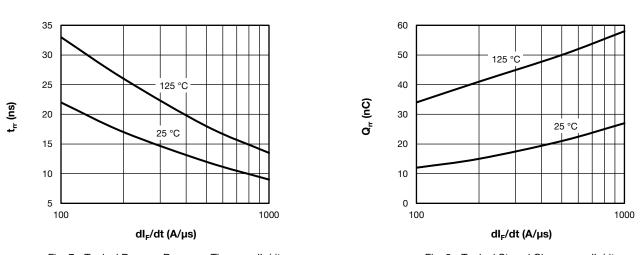


Fig. 7 - Typical Reverse Recovery Time vs. dl<sub>F</sub>/dt

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**ISHAY** 



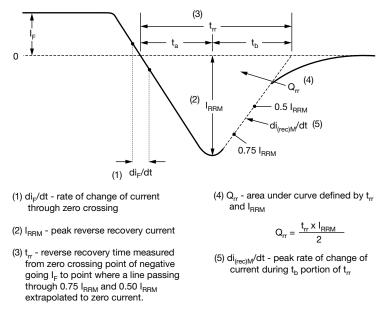


Fig. 9 - Reverse Recovery Waveform and Definitions

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## **ORDERING INFORMATION TABLE**

**VISHAY** 

| Device code | VS- | 6      | С                    | v               | н         | 01      | н       | М3      |
|-------------|-----|--------|----------------------|-----------------|-----------|---------|---------|---------|
|             |     | 2      | 3                    | 4               | 5         | 6       | 7       | 8       |
|             | 1   | · Visł | nay Sen              | niconduc        | ctors pro | oduct   |         |         |
|             | 2 - | Cur    | rent rati            | ng (6 =         | 6 A)      |         |         |         |
|             | 3 - | Circ   | uit conf             | iguratior       | ו:        |         |         |         |
|             |     | C =    | commo                | n catho         | de        |         |         |         |
|             | 4 - | - V =  | SlimDP               | AK              |           |         |         |         |
|             | 5   |        | cess typ<br>hyper fa | e,<br>ast recov | /ery      |         |         |         |
|             | 6 - | · Volt | tage coo             | de (01 =        | 100 V)    |         |         |         |
|             | 7 - | H =    | AEC-Q                | 101 qua         | lified    |         |         |         |
|             | 8 - | M3     | = halog              | en-free,        | RoHS-     | complia | nt, and | termina |

| ORDERING INFORMATION (Example) |  |      |                                   |  |  |  |  |
|--------------------------------|--|------|-----------------------------------|--|--|--|--|
| PREFERRED P/N                  | QUANTITY PER REEL MINIMUM ORDER QUANTITY PACKAGING DESCRIPTION |      |                                   |  |  |  |  |
| VS-6CVH01HM3/I                 | 4500   | 4500 | 13"diameter plastic tape and reel |  |  |  |  |

| LINKS TO RELATED DOCUMENTS |                          |  |  |  |  |
|----------------------------|--------------------------|--|--|--|--|
| Dimensions                 | www.vishay.com/doc?96081 |  |  |  |  |
| Part marking information   | www.vishay.com/doc?96085 |  |  |  |  |
| Packaging information      | www.vishay.com/doc?88869 |  |  |  |  |

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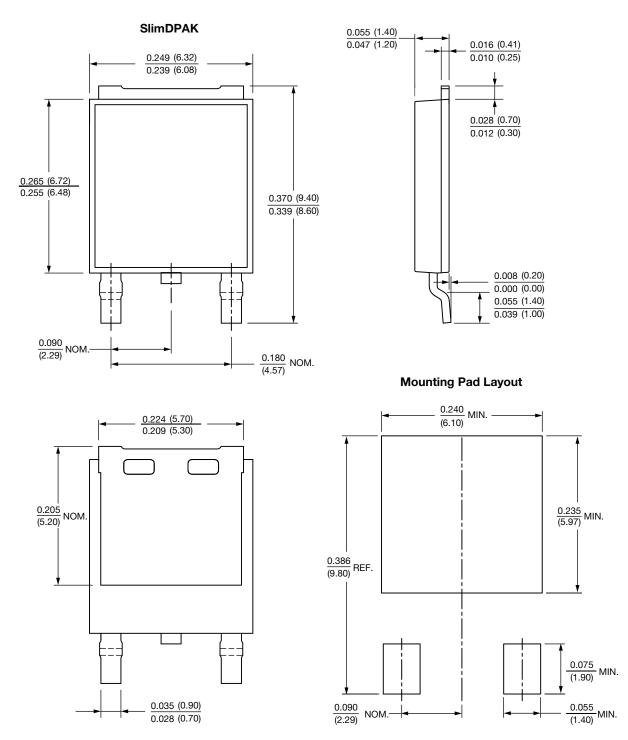


# **Outline Dimensions**

**Vishay Semiconductors** 

SlimDPAK

**DIMENSIONS** in inches (millimeters)



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